## NSN 5961-01-651-0369

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-651-0369 **Inclosure Material:** Plastic **Overall Length:** 2.10 millimeters **Overall Height:** 1.00 millimeters **Overall Width:** 2.00 millimeters **End Application:** 4935-01-136-0233 Voltage Rating In Volts Per Characteristic: 40.00 source supply voltage **Current Rating Per Characteristic:** 200.00 milliamperes source current **Power Rating Per Characteristic:** 200.00 milliwatts total power dissipation **Product Name:** Schottky barrier diode arrays **Special Features:** Weight: 0.006 grams; finish: matte tin; case: sot-363; mounting type: surface mount; 3000 count tape and reel; storage temperature: -65.00 deg. C to 125.00 deg. C.; operating temperature: -55.00 deg. C. To 125.00 deg. C.; Shelf Life: N/a **Unit Of Measure:**